L Number	Hits	Search Text	DB .	Time stamp
-	705	438/30.ccls.	USPAT;	2004/10/06 18:11
			US-PGPUB	
-	938	438/151.ccls. not (438/30.ccls.)	USPAT;	2004/10/06 18:51
			US-PGPUB	
-	314	438/158.ccls. not (438/151.ccls.	USPAT;	2004/10/06 19:54
		438/30.ccls.)	US-PGPUB	
-	66	438/609.ccls. not (438/158.ccls.	USPAT;	2004/10/06 19:54
		438/151.ccls. 438/30.ccls.)	US-PGPUB	
-	195		USPAT;	2004/10/12 14:57
		(single near etch\$7)	US-PGPUB	
-	17		USPAT;	2004/10/12 14:32
		(single near etch\$7)) and ((single near	US-PGPUB	
		etch\$7) with (source drain))		
-	11	"5874326"	USPAT;	2004/10/12 14:40
			US-PGPUB	
-		"5874326"	DERWENT	2004/10/12 14:40
	20	,	DERWENT	2004/10/12 14:56
		U14-K01A2B).epi.		
-	1	(L03-C03 and L03-G05A and L04-C07 and	DERWENT	2004/10/12 14:56
		L04-E01).cpi.		
-	313	, , ,	USPAT;	2004/10/12 14:58
		((reduc\$5 near mask\$5))	US-PGPUB	`
-	52	(((thin adj film adj transistor\$1) TFT) and	USPAT;	2004/10/12 17:42
		((reduc\$5 near mask\$5))) and (bottom near	US-PGPUB	1
	_	gate)		10004/00/00 00 00
-	2	(bottom adj gate) and ((single near etch\$5) with (source drain))	USPAT;	2004/10/12 15:33
İ	1.5		US-PGPUB	2004/10/10 17 42
_	15	((thin adj film adj transistor\$1) TFT) and (photo\$letching\$1process)	USPAT; US-PGPUB	2004/10/12 17:43
_	3212	(thin adj film adj transistor) and (etch\$5	USPAT;	2004/10/13 13:10
_	3212	with (gate near (electrode layer line	US-PGPUB	2004/10/13 13:10
		conductor)))	03-FGF0B	
_	1074	((thin adj film adj transistor) and (etch\$5	USPAT;	2004/10/13 13:11
	10/4	with (gate near (electrode layer line	US-PGPUB	2004/10/13 13:11
		conductor)))) and (etch\$5 with (gate near	03-FGF0B	
		(electrode layer line conductor)) with		
		(source drain))		
		(bource draffi)		<u> </u>